

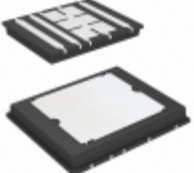
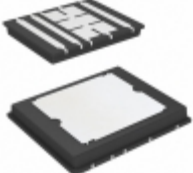
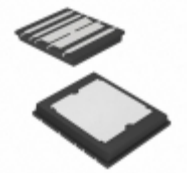
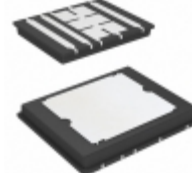
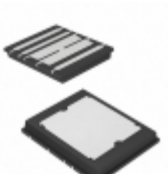
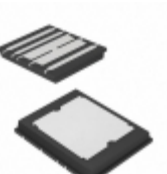

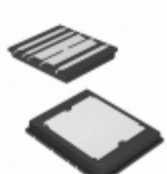
	<h2>SIE802DF-T1-E3</h2>
	<p>Hersteller-Teilenummer: SIE802DF-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 60A 10-POLARPAK</p> <p>Datenblätter:  SIE802DF-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 793 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIE802DF-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 60A 10-POLARPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	793 pcs Stock
Hersteller Standard Vorlaufzeit	27 Weeks
detaillierte Beschreibung	N-Channel 30V 60A (Tc) 5.2W (Ta), 125W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	10-PolarPAK® (L)
Supplier Device-Gehäuse	10-PolarPAK® (L)
Verlustleistung (max)	5.2W (Ta), 125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Tc)
Rds On (Max) @ Id, Vgs	1.9 mOhm @ 23.6A, 10V
VGS (th) (Max) @ Id	2.7V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	160nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	7000pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SIE802DF-T1-E3TR

SIE802DF-T1-E3 ist neu im Original, Suche SIE802DF-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIE802DF-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SIE802DF-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIE802DF-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 60A POLARPAK</p>	 <p>SIE806DF-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A 10- POLARPAK</p>	 <p>SIE804DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 37A POLARPAK</p>	 <p>SIE802DF-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 60A 10- POLARPAK</p>
 <p>SIE800DF-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 50A POLARPAK</p>	 <p>SIE800DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 50A POLARPAK</p>	 <p>SIE802DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A POLARPAK</p>	 <p>SIE800DF-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 50A 10- POLARPAK</p>

heiße Teile

Mehr

08055A500GAT2A	12065G334ZAT4A	130MT100KB	D 184-5705-7050	AP85U03GMT-HF
CP0603B1747CSTR	CS0603KRX7R8BB273	D FYPF1004DN	G7L-1A-B	GRM32NF51C106ZA01L
IR1166STRPBF	LM431BIZX	MEE140-12DA	MMBZ5241BLT1G	N490CH16
D NXA025A0X-S	P300CH09F2K0	PC6-24-5	R3047TD28R	SIE01-03
SIE01-06	SIE20031	SIE20034	SIE501.8LT	SIE503.3LT
SIE503.3LTR	SIE800DF-T1-E3	D SIE800DF-T1-E3	SIE802DF-T1-E3	SIE808DF-T1-E3
SIE808DF-T1-E3	D SIE812DF	SIE848DF-T1-E3	SIE848DF-T1-E3	SIE862DF-T1-GE3
SIE862DF-T1-GE3	SIE864DP-T1-GE3	SIE874DF-T1-GE3	SIE874DF-T1-GE3	SKII09NAC125T10
SKM300GB170D	SKM75GB128DN	SKY66117-11	D SW15PCN075	TK11128ASIL
TPIC1338DBTRG4	USB2504-JT	W1263YH240	W3270NC22A	XC8101AA01MR-R

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